



### **BAV19WS-BAV21WS SWITCHING DIODE**



### **Features**

- Fast Switching Speed
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose Switching Applications
- High Conductance
- This is a Halogen Free Device
- "-A" is an AEC-Q101 qualified device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

# Schematic & Pin Configuration



### **Mechanical Characteristics**

- Case: SOD-323, Molded plastic
- Terminals: Plated leads solderable per MIL-STD-202, Method 208

### Maximum Ratings@T<sub>A</sub>=25°C unless otherwise specified

Characteristic	Symbol	BAV19WS	BAV20WS	BAV21WS	Unit
Marking Code		A8	T2	Т3	
Non-Repetitive Peak Reverse Voltage	V <sub>RM</sub>	120	200	250	V
Peak Repetitive Peak Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	100	150	200	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	71	106	141	
Average Rectified Output Current	Io	200			mA
Forward continuous current	I <sub>FM</sub>	400		mA	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)  @t=1.0ms @ t=1.0s	I <sub>FSM</sub>	2.5 0.5		А	
Power Dissipation	P <sub>d</sub>	250		mW	
Repetitive Peak Forward Current	I <sub>FRM</sub>	625		mA	
Typical Thermal Resistance Junction to Ambient	R <sub>θJA</sub>	500		°C/W	
Junction Temperature Range	TJ	150		°C	
Storage Temperature Range	T <sub>STG</sub>	-55 to +150		°C	

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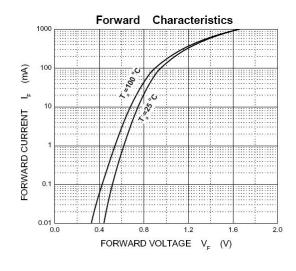


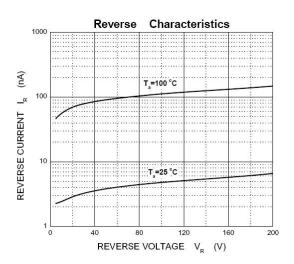
# Electrical Characteristics@T<sub>A</sub>=25°C unless otherwise specified

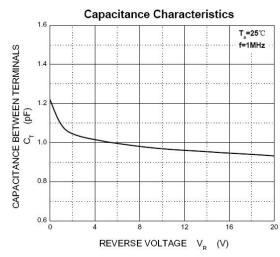
Characteristic	Symbol	Test Condition	Min	Тур	Max	Unit
Forward Voltage*	\/ <del>-</del>	I <sub>F</sub> =100mA I <sub>F</sub> =200mA	-	0.95 1.06	1.00 1.25	V
Reverse Leakage Current*  BAV19WS BAV20WS BAV21WS	IR	V <sub>R</sub> =100V V <sub>R</sub> =150V V <sub>R</sub> =200V	-	0.007	0.1	μA
Diode capacitance	Ст	V <sub>R</sub> =0V,f=1.0MHz	-	1.2	5	pF
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> = I <sub>R</sub> =30mA, I <sub>rr</sub> =0.1×I <sub>R</sub> ,R <sub>L</sub> =100 Ω	-	-	50	ns

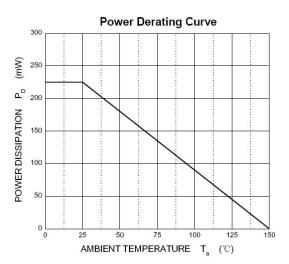
<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

## **Ratings and Characteristics Curves**









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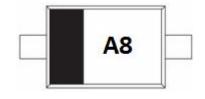


# **Ordering Information**

Device	Package	Shipping
BAV19WS-BAV21WS	SOD-323	3000pcs / reel
BAV19WSTR-BAV21WSTR	SOD-323	3000pcs / reel

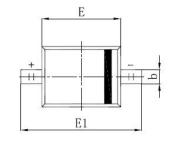
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

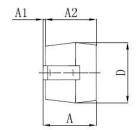
# **Marking Diagram**

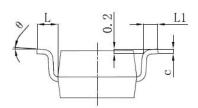


A8 = Marking Code

## **Mechanical Dimensions SOD-323**

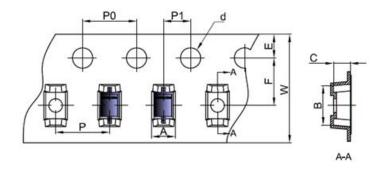






0)41701	Millimeters		Inc	hes	
SYMBOL	MIN.	MAX.	MIN.	MAX.	
Α	-	1.000	-	0.039	
A1	0.000	0.100	0.000	0.004	
A2	0.800	0.900	0.031	0.035	
b	0.250	0.350	0.010	0.014	
С	0.080	0.150	0.003	0.006	
D	1.200	1.400	0.047	0.055	
E	1.600	1.800	0.063	0.071	
E1	2.500	2.700	0.098	0.106	
L	0.475 REF.		0.019 REF.		
L1	0.250	0.400	0.010	0.016	
θ	0°	8°	0°	8°	

# **Carrier Tape Specification SOD-323**



SYMB	Millimeters		
OL	Min.	Max.	
В	2.85	2.95	
С	1.20	1.30	
d	1.40	1.60	
E	1.65	1.85	
F	3.40	3.60	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
W	7.90	8.30	

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